Table 1

	Element	H_{O}	Te	θ_{D}	γ exp (mJ/K ² mol)	γ calc (mJ/K ² mol)
		(Oe)	(°K)	(oK)	(mJ/K²mol)	(mJ/K2mo1)
	GaI	59.3	1.08	317	0.598 [10]	1.02
	GaII	620	6.24	200 [2]	1.63	0.92
	Al	103	1.17	423	1.36 [10]	0.90
	In	293	3.39	108	1.70 [10]	1.23

1 illustrate the relationship between Al, GaII and In.

In addition the question whether the change of the electron-phonon coupling constant or the increase in the density of states is responsible for both the high $T_{\rm C}$ and the high γ of GaII, compared with GaI, can be answered. We may do this by using an expression for $T_{\rm C}$ given by Jensen and Maita [5] and by McMillan [6]. Moreover we use an expression for γ due to Migdal [7].

$$T_{\rm c} = 0.69 \,\theta_{\rm D} \,\exp\{-(1+\lambda)/(\lambda-\mu^*)\}$$
 (2)

$$\gamma \propto N(E_{\rm F})(1+\lambda)$$
 (3)

Here λ denotes the electron-phonon coupling constant, μ^* is the effective Coulomb interaction and θ_D is the Debye temperature. $N(E_F)$ is the band structure density of states at the Fermi surface. μ^* is taken to be 0.10, a value which has recently been confirmed by isotope effect measurements [8]. Assuming $\lambda = N(E_F) \cdot V_{\rm ph}$ it turns out that $V_{\rm ph}$, the electron-phonon interaction coefficient, is decreased by going from GaI to GaII, while the density of states at the Fermi surface is increased by a factor of 2.3.

According to Ziman [9] we may also write

$$\lambda \approx C^2/M \,\theta_{\rm D}^2 \tag{4}$$

where M is the atomic mass and C is a measure

for the rigid-ion potential in the electron-phonon interaction. The change from GaI to GaII decrease C^2 by a factor of about 1.4. It may be, however, that the uncertainty in θ_D in the high pressure phase [2] is too large to make any reliable conclusions.

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